

Surface Mount Schottky Barrier Rectifier
Reverse Voltage - 40 and 60 V
Forward Current - 2.0A
Features

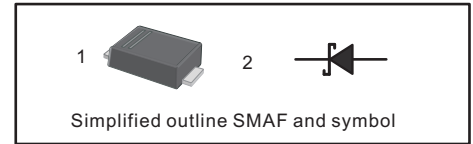
- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: SMAF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 27mg 0.00086oz

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode


Absolute Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	SSL24F	SSL26F	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	40	60	V
Maximum RMS voltage	V_{RMS}	28	42	V
Maximum DC Blocking Voltage	V_{DC}	40	60	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	2.0		A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	50	40	A
Max Instantaneous Forward Voltage at 2A	V_F	0.45	0.52	V
Maximum DC Reverse Current $T_a = 25^{\circ}C$ at Rated DC Reverse Voltage $T_a = 100^{\circ}C$	I_R	0.5 10	0.3 5	mA
Typical Junction Capacitance ¹⁾	C_j	290	130	pF
Operating Junction Temperature Range	T_j	-55 ~ +125		°C
Storage Temperature Range	T_{stg}	-55 ~ +150		°C

1) Measured at 1MHz and applied reverse voltage of 4 V D.C.

Fig.1 Forward Current Derating Curve

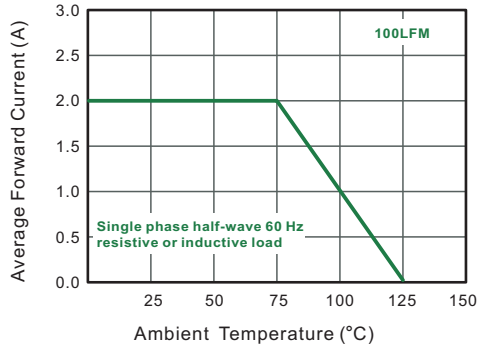


Fig.2 Typical Reverse Characteristics

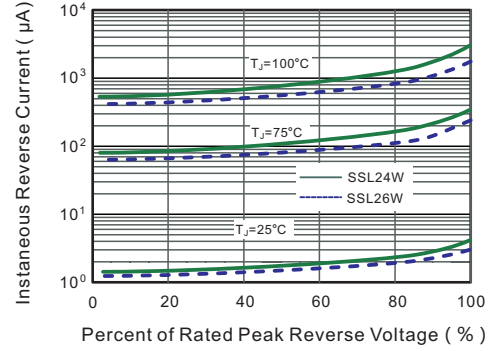


Fig.3 Typical Forward Characteristic

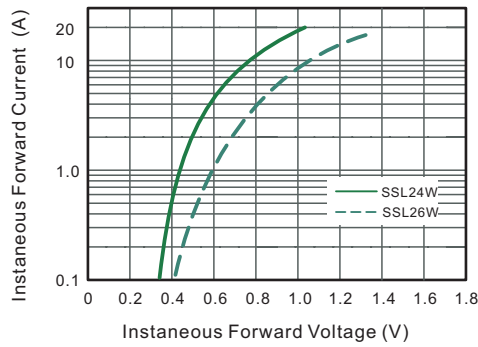


Fig.4 Typical Junction Capacitance

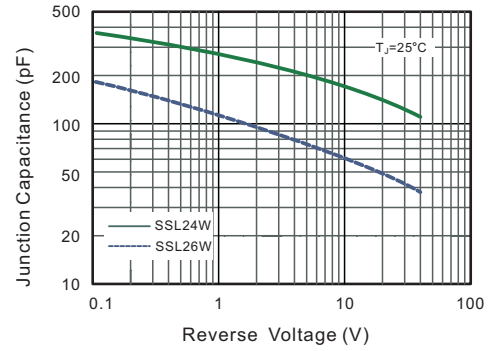
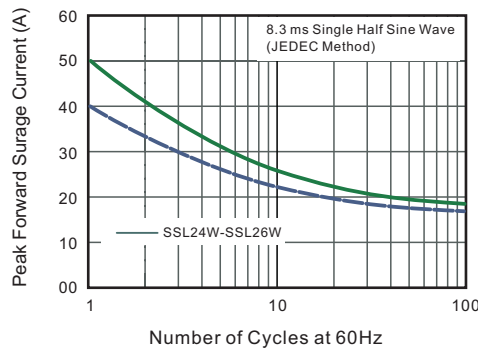


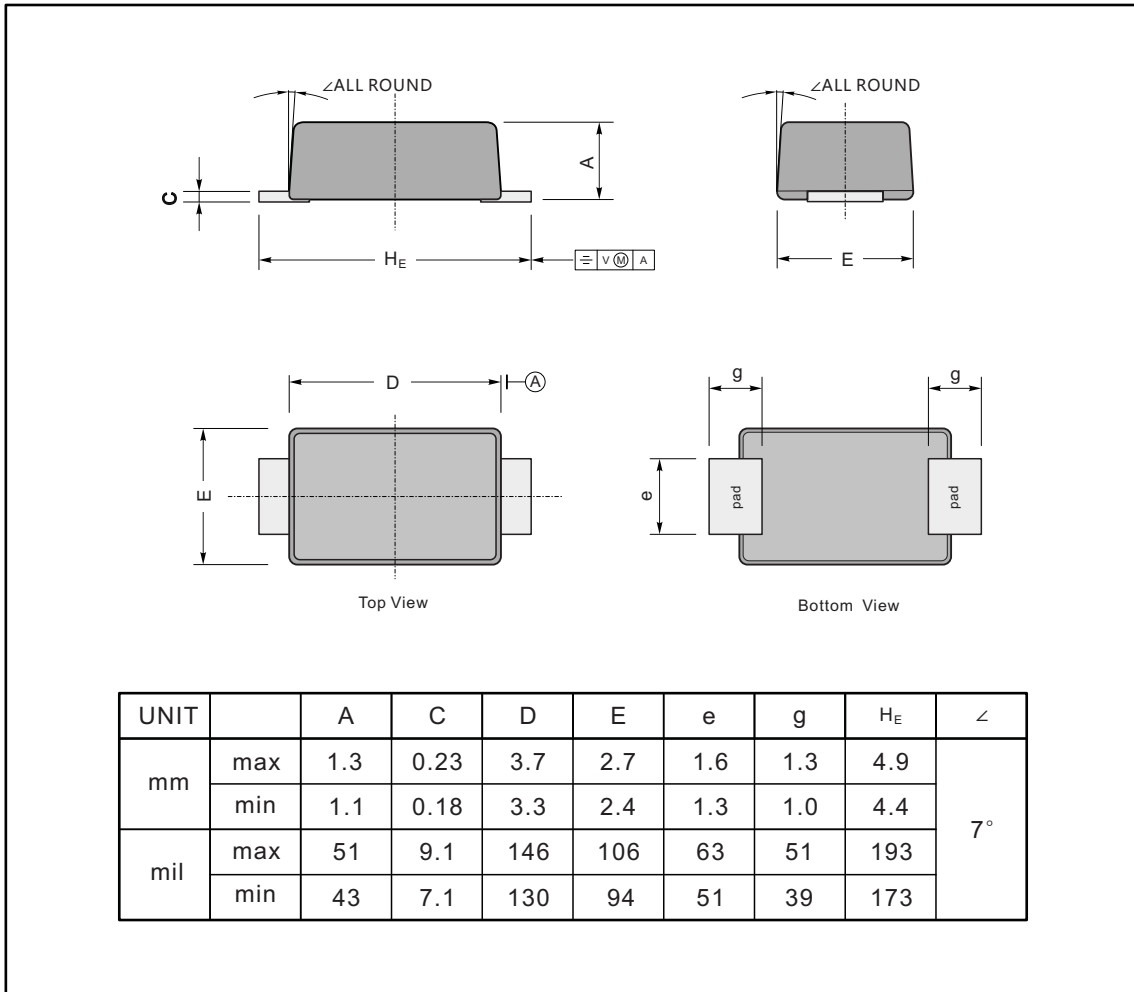
Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



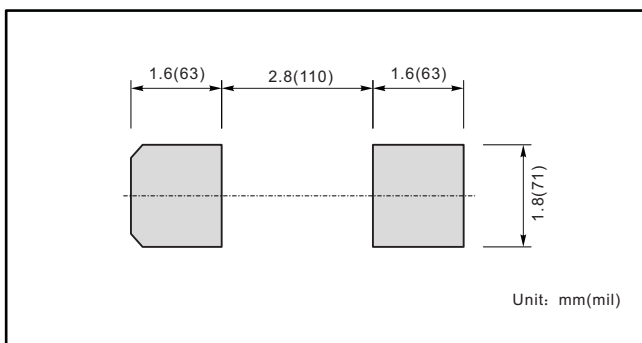
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SMAF



The recommended mounting pad size



Marking

Type number	Marking code
SSL24F	SSL22
SSL26F	SSL24